Bluetooth® Technology Solutions — SiW1722

RF Micro Devices[®] Offers the SiW1722[™] UltimateBlue[™] Radio Modem

REPUBLICES MICRO-DEVICES SIW1722*

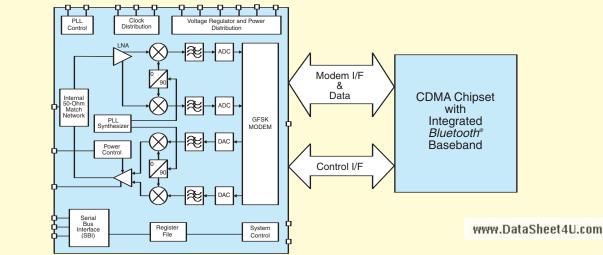
The SiW1722[™] UltimateBlue[™] radio modem is a thirdgeneration radio modem for *Bluetooth*[®] wireless communications and is based on 0.18 µm CMOS technology. The highly integrated transceiver was specifically designed to meet the rigorous RF performance required for integrating *Bluetooth* technology into CDMA-based mobile phone applications.

The SiW1722 radio modem combines a 2.4 GHz radio transceiver and Gaussian Frequency Shift Keying (GFSK) modem with digital control functions. The IC also incorporates analog and digital voltage regulators, a power-on-reset (POR) circuit and a reference Phase Lock Loop (PLL) to enable multiple input frequencies.

The SiW1722 radio modem uses direct conversion (zero-IF) architecture. This allows digital filtering for excellent interference rejection as compared to low IF solutions, which have lower rejection due to analog matching limitations. The receiver features high sensitivity due to a low noise RF design combined with an advanced modem design. A fast hardware AGC enables full discovery of any device within the dynamic range of the receiver, solving near-far issues. The transmitter can maintain a stable output power level up to +4 dBm for class 2 operation, which in combination with the excellent receiver performance, ensures the maximum possible range at the lowest system cost.

Features

- → On-chip 50 Ohm RF match network with no external impedance matching components
- → Fully compliant with *Bluetooth* specification 1.2
- Digital interface to CDMA chipsets with an integrated Bluetooth baseband
- → Supports multiple external reference clocks or crystal frequencies with on-chip reference PLL
- Direct-conversion architecture with no external channel filter or VCO resonator components
- → Highly sensitive receiver with excellent interference rejection performance
- → Hardware AGC dynamically adjusts receiver performance in changing environments
- → Low out-of-band spurious emissions prevents interference with mobile phone frequencies
- → Class 2 and 3 transmit output power up to +4 dBm output power control loop for accurate power control
- On-chip voltage regulation simplifies voltage input requirement
- → Low power consumption in active and standby modes



SiW1722 Block Diagram

RADIO SPECIFICATIONS

 $C/I \ge 3$ MHz (0.1% BER)

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Parameter	Min	Тур	Max	Units
Supply voltage to on-chip regulator	2.3	—	3.63	V
Operating temperature (industrial grade)	-40	—	+85	°C
Receiver sensitivity		-87		dBm
Output power, maximum		+2	+4	dBm
Maximum usable signal	0	_		dBm
Frequency operating range	2402	_	2480	MHz
C/I co-channel (0.1% BER)		+8		dB
C/I 1 MHz (0.1% BER)		-4	_	dB
C/I 2 MHz (0.1% BER)		-38	_	dB

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For sales or technical support, contact RFMD at 336-678-5570 or sales-support@rfmd.com





dB

Enabling Wireless Connectivity™

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